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Diazazethrene bisimide: a strongly electron-accepting π -system synthesized *via* the incorporation of both imide substituents and imine-type nitrogen atoms into zethrene†

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The development of highly electron-accepting π -systems is a fundamentally challenging issue despite their potential applications as high-performance n-type organic semiconductors, organic rechargeable batteries, and stable redox-active organocatalysts. Herein, we demonstrate that the incorporation of both imide substituents and imine-type nitrogen atoms into zethrene affords the strongly electron-accepting π -system diazazethrene bisimide (DAZBI). DAZBI has a low-lying LUMO (-4.3 eV vs. vacuum) and is readily reduced by the weak reductant L-ascorbic acid to afford the corresponding dihydro species. The injection of two electrons into DAZBI provides the corresponding dianion. These reduced species display remarkable stability, even under ambient conditions, and an intense red fluorescence. A DAZBI dimer, which was also synthesized, effectively accommodated four electrons upon electron injection.

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Introduction

Organic π -conjugated molecules are inherently electron-donating because their π -electrons are weakly bound to the nuclei. Hence, increasing the electron-accepting ability of π -conjugated molecules is an essential challenging issue. Electron-accepting π -systems are highly useful molecules in organic chemistry and materials science. These molecules are predisposed to the injection of electrons, thus enabling their applications in organic electronic devices and photosensitizers. In organic electronic devices, they are used in n-type organic field-effect transistors,¹ organic photovoltaic devices,² and as active materials in battery electrodes.^{3,4} As photosensitizers, they are key components in photoredox reactions^{5,6} as well as in photodynamic and photothermal therapy.⁷ To create effective electron-accepting π -systems, the stabilization of the lowest unoccupied molecular orbital (LUMO) is crucial. Lowering the

LUMO energy is also beneficial for improving the air stability of the reduced species, which often appear as intermediates in the aforementioned materials. Furthermore, decreasing the π -electron density is advantageous for relieving intermolecular exchange repulsion to allow closer molecular contact, thus enhancing electron mobility *via* effective orbital overlap in the solid state.

Zethrene **1** (Fig. 1) is a polycyclic aromatic hydrocarbon with inherent electron-accepting properties that undergoes electron injection at -1.76 V (vs. Fc/Fc⁺).^{8,9} Its reduction potential is significantly higher than that of anthanthrene (-2.11 V) despite having a similar composition (zethrene: C₂₄H₁₄; anthanthrene: C₂₂H₁₂).¹⁰ Wu and co-workers have reported zethrene bisimide

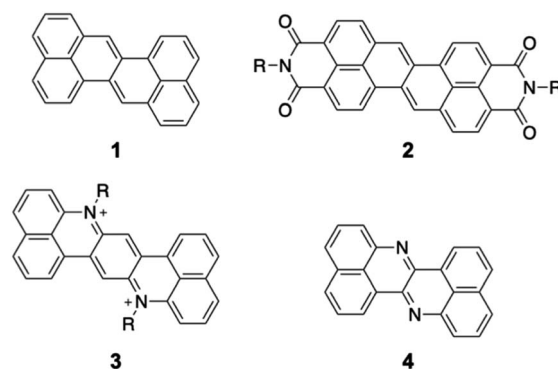


Fig. 1 Selected examples of zethrene derivatives.

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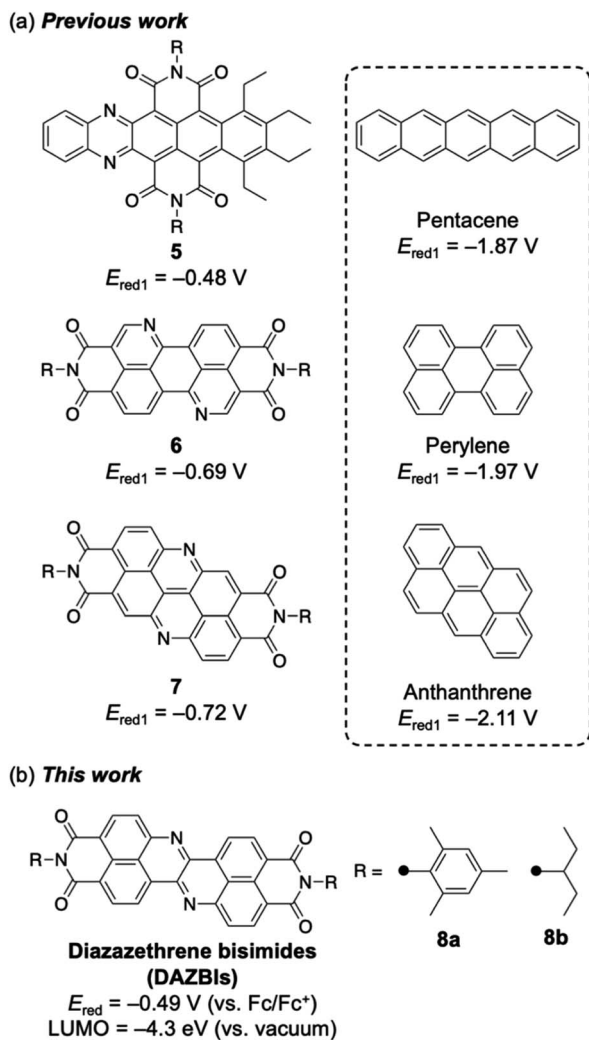


Fig. 2 (a) Selected examples of the incorporation of both imide substituents and imine-type nitrogen atoms. (b) Diazazethrene bisimides. The first reduction potentials (E_{red1}) are standardized relative to the ferrocene/ferrocenium couple (Fc/Fc^+).

2, which undergoes its first reduction at -0.84 V (vs. Fc/Fc^+).¹¹ The same group has also synthesized the nitrogen-doped zethrenium dication **3**.¹² Recently, Fujimoto and co-workers have reported nitrogen-doped zethrene **4**, which shows, in comparison to zethrene, enhanced electron-affinity and reactivity toward nucleophiles.¹³ These results suggest that the structural modification of zethrene can afford strongly electron-accepting π -systems.

Two effective strategies exist to create highly effective electron-accepting compounds *via* the chemical modification of existing π -systems. One is the functionalization of the periphery with electron-withdrawing imide groups. For example, rylene diimides such as naphthalene diimide (NDI)¹⁴ and perylene bisimide (PBI)¹⁵ have significantly lower LUMOs than those of their parent rylenes. The other strategy is the replacement of carbon atoms with more electronegative elements, such as nitrogen atoms.^{16–18} These two strategies have usually been implemented independently.

Recently, several researchers have reported the incorporation of both nitrogen atoms and imide substituents to achieve strongly electron-accepting π -systems.^{19–27} Such a dual modification benefits from the aforementioned properties of both the imide groups and the imine-type nitrogen atoms. Selected examples are shown in Fig. 2a. Wang and co-workers have reported the integration of both nitrogen atoms and imide substituents into pentacene **5**, which exhibits a relatively high reduction potential (-0.48 V vs. Fc/Fc^+).¹⁹ Okamoto and co-workers have demonstrated that nitrogen-doped PBI **6** acts as a robust n-type semiconductor.^{20–22} Our groups have recently reported the synthesis of a nitrogen-doped anthanthrene derivative with two imide substituents (**7**), which exhibits a relatively high electron mobility ($0.90 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$) in a single crystal and affords an air-stable radical anion upon electron injection.²³ In each of these cases, the dual incorporation of two imide groups and two imine-type nitrogen atoms stabilized the LUMO level by *ca.* 1.3 eV. Herein, we report the synthesis and properties of diazazethrene bisimide (DAZBI) **8**, a molecule designed during the course of our research into creating new functional π -systems by combining NDI subunits with additional heteroatoms (Fig. 2b).^{23,28–30}

Results and discussion

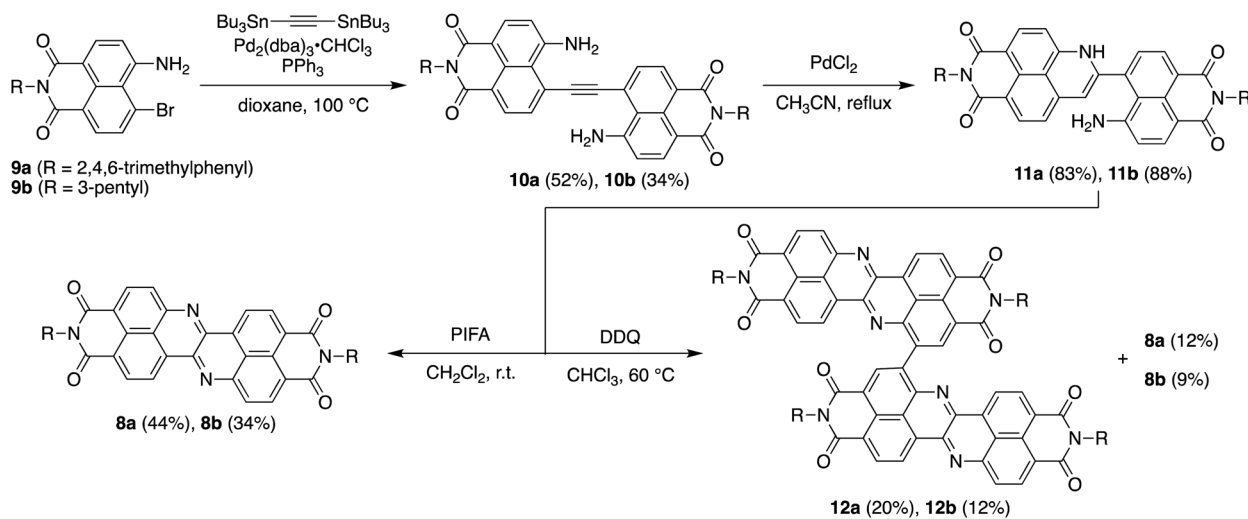
Synthesis

Scheme 1 depicts the synthesis of DAZBI **8** starting from the 4-bromo-5-aminonaphthalene monoimides **9a** ($\text{R} = 2,4,6$ -trimethylphenyl) and **9b** ($\text{R} = 3$ -pentyl), which were synthesized according to literature methods.^{23,31} The palladium-catalyzed Migita–Kosugi–Stille cross-coupling^{32,33} of **9a** and **9b** with bis(tributylstannyl)acetylene produced the corresponding ethynylene-linked dimers **10a** and **10b** in 52% and 34% yield, respectively. The palladium-catalyzed intramolecular hydroamination of **10a** and **10b** generated precursors **11a** and **11b** as enamines in 83% and 88% yield, respectively. Subsequent oxidation of the enamines with bis(trifluoroacetoxy)iodobenzene (PIFA) afforded DAZBIs **8a** and **8b** in 44% and 34% yield, respectively. Interestingly, the treatment of precursors **11a** and **11b** with 2,3-dichloro-5,6-dicyano-*p*-benzoquinone (DDQ) yielded the directly linked dimers **12a** and **12b** together with monomers **8a** and **8b**, respectively. The attempted oxidative dimerization of **8a** and **8b** with DDQ did not proceed (Fig. S66†). At present, we speculate that the radical coupling of the azaphenalenyl intermediates **11a** and **11b** generated dimers **12a** and **12b** (Scheme S1†).

Structural analysis

The structure of **8a** was determined unequivocally *via* a single-crystal X-ray diffraction analysis (Fig. 3).³⁴ DAZBI **8a** adopts a Z-shaped structure, wherein the mean plane deviation of the central π -system is 0.044 \AA , which indicates high planarity. The length of the C26–N1 bond ($1.277(5) \text{ \AA}$), which links the central nitrogen atom with the fused ethene unit, is shorter than that of the C4–N1 bond ($1.400(6) \text{ \AA}$) connecting the central nitrogen atom to the naphthalene monoimide unit. The C4–N1–C26





Scheme 1 Synthesis of DAZBI monomers and dimers.

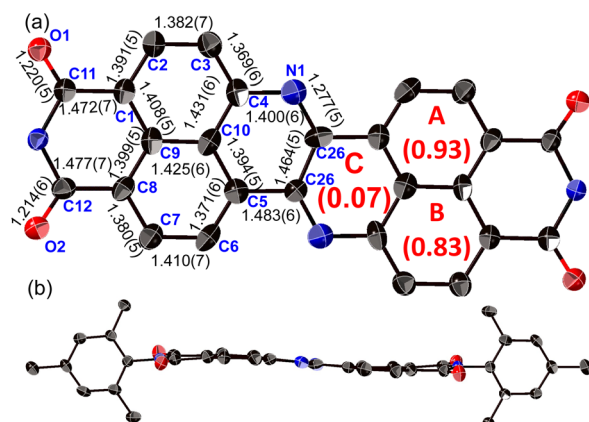


Fig. 3 X-ray crystal structure of **8a** with thermal ellipsoids at 50% probability. (a) Top view and (b) side view. All hydrogen atoms and solvent molecules are omitted for clarity. In (a), the 2,4,6-trimethylphenyl groups are omitted for clarity.

angle ($117.7(4)^\circ$) is slightly smaller than that of an ideal hexagon (120°). Furthermore, the harmonic oscillator model of aromaticity (HOMA) value³⁵ for ring C (0.07) is smaller than the HOMA values for rings A (0.93) and B (0.83), indicative of a substantial bond-length alternation in ring C. These results suggest the structure is characterized by the contribution of the 1,4-diaza-1,3-butadiene-like structure in the center. A similar trend was observed for the parent zethrene.⁹

The X-ray crystal structure of dimer **12b** is shown in Fig. 4. The two DAZBI moieties are crystallographically equivalent. Each dimer unit was separated by co-crystallized solvent molecules of *o*-xylene. The DAZBI planes are twisted with a dihedral angle of 53° . The mean plane deviation of each DAZBI moiety (0.030 \AA) is comparable to that of DAZBI monomer **8a** (0.044 \AA). Judging from the C11–N2 bond lengths ($1.277(5) \text{ \AA}$), the central nitrogen atoms retain their imine-type character (Fig. S41†). Interestingly, the HOMA value for ring C in dimer **12b** (0.49) is

higher than the HOMA value in monomer **8a** (0.07), suggesting that the two DAZBI subunits in **12b** are efficiently conjugated.

Optical and electrochemical properties

The UV/vis absorption and emission spectra of DAZBI monomer **8a** and dimer **12a** in CH_2Cl_2 are shown in Fig. 5. DAZBI monomer **8a** exhibits intense and well-resolved absorption bands in the 500–700 nm range. This spectral feature is similar to those observed for zethrene **1** ($\lambda_{\text{Abs}} = 550 \text{ nm}$),⁹ zethrene bisimide **2** ($\lambda_{\text{Abs}} = 648 \text{ nm}$),¹¹ and 7,14-diazazethrene **4** ($\lambda_{\text{Abs}} =$

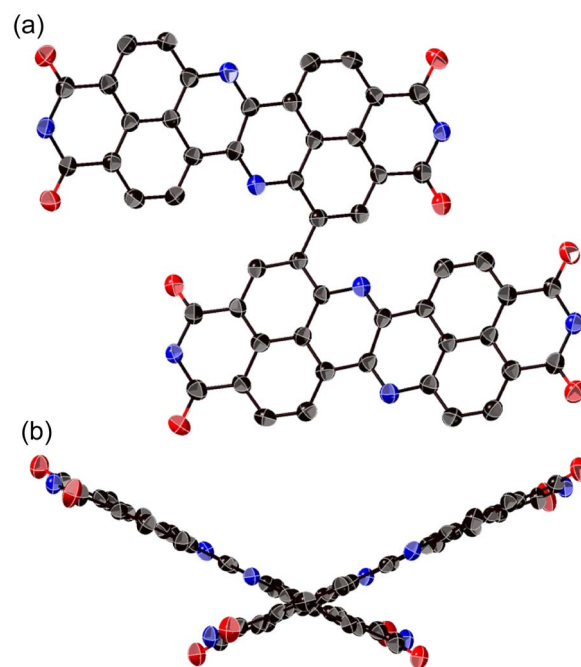


Fig. 4 X-ray crystal structure of **12b** with thermal ellipsoids at 50% probability. (a) Top view and (b) side view. All hydrogen atoms, the 3-pentyl groups, and solvent molecules are omitted for clarity.



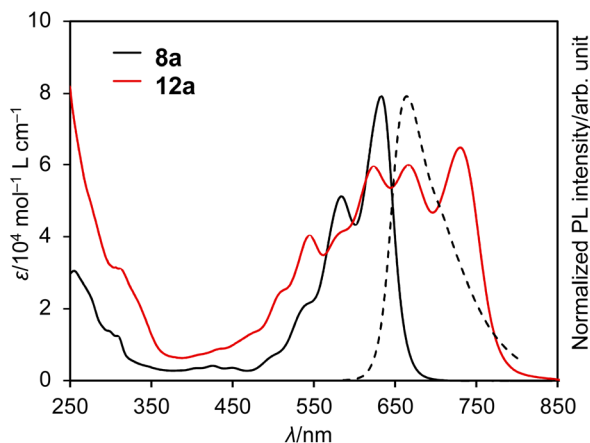


Fig. 5 UV/vis absorption spectra of **8a** and **12a** (solid lines) and emission spectrum of **8a** (dashed line); solvent: CH_2Cl_2 ; λ : wavelength; ϵ : extinction coefficient; $\lambda_{\text{ex}} = 550$ nm.

568 nm).¹³ The absorption spectrum of DAZBI **8a** ($\lambda_{\text{Abs}} = 633$ nm) is drastically red-shifted compared to those of diazaperylene bisimide **6** ($\lambda_{\text{Abs}} = 520$ nm)²⁰ and diazaanthanthrene bisimide **7** ($\lambda_{\text{Abs}} = 497$ nm),²³ indicating that the choice of a zethrene core for the application of the current design concept: the incorporation of both imide substituents and imine-type nitrogen atoms, is critical to realize the responsivity in a long wavelength region. DAZBI **8a** moreover shows red fluorescence with a quantum yield of 0.10 and a lifetime of 1.7 ns. These parameters afford a radiative decay rate constant (k_r) and the sum of non-radiative and intersystem crossing decay rate constants ($k_{\text{nr}} + k_{\text{ISC}}$) of $6.5 \times 10^7 \text{ s}^{-1}$ and $5.0 \times 10^8 \text{ s}^{-1}$, respectively. The emission spectrum is the mirror image of the absorption spectrum with a small Stokes shift of 436 cm^{-1} . These results, combined with the presence of a clear vibrational structure, confirms that **8a** is structurally rigid. On the other hand, the spectrum of DAZBI dimer **12a** has multiple absorption bands that are bathochromically shifted relative to those of **8a**. The wavelength of the absorption onset (*ca.* 800 nm) is red-shifted compared to that of monomer **8a** (*ca.* 700 nm), suggesting that the two DAZBI subunits are efficiently conjugated. The emission spectrum of **12a** in solution was too weak to be recorded, probably because the rotation around the single bond between the two DAZBI units induces a fast relaxation of its excited state.

Subsequently, we evaluated the electron affinity of **8a** and **12a** using cyclic voltammetry (Fig. S43–S45† and Table 1). The

voltammograms were obtained in CH_2Cl_2 using 0.1 M $[\text{Bu}_4\text{N}][\text{PF}_6]$ as the supporting electrolyte and a Ag/AgNO_3 reference electrode; all potentials are given relative to the ferrocene/ferrocenium couple (Fc/Fc^+). DAZBI monomer **8a** exhibits two reversible reduction waves at -0.49 V and -0.73 V (Table 1, line 1). The first reduction potential of **8a** is shifted positively by 0.35 V and 0.84 V relative to those of zethrene bisimide **2** (-0.84 V)¹¹ and 7,14-diazazethrene **4** (-1.33 V),¹³ respectively. Furthermore, the first reduction potential of **8a** (-0.49 V) is even higher than those of nitrogen-doped PBI **6** (-0.69 V)²⁰ and nitrogen-doped anthanthrene bisimide **7** (-0.72 V),²³ highlighting that the choice of a zethrene core for the application of the current design concept: the incorporation of both imide substituents and imine-type nitrogen atoms, is critical to realize high electron-accepting ability. According to the experimentally obtained reduction potential of **8a**, its LUMO level was calculated to be -4.3 eV (*vs.* vacuum), which satisfies the criterion needed to be considered an air-stable electron-transporting material (< -4.0 eV *vs.* vacuum).^{36,37} The oxidation wave of **8a** was irreversible and, using differential pulse voltammetry, the first oxidation potential was determined to be 1.24 V (*vs.* Fc/Fc^+). The electrochemical HOMO–LUMO gap for **8a** is 1.73 V. The cyclic voltammogram obtained for **12a** shows a reversible four-step reduction process and an irreversible oxidation wave. The first reduction and oxidation potentials are -0.36 V and 1.07 V, respectively (Table 1, line 3). The reduction potential of **12a** is equal to that of *p*-chloranil (-0.36 V),³⁸ a common mild oxidant. The electrochemical HOMO–LUMO gap for **12a** (1.43 V) is narrower than that of DAZBI monomer **8a** (1.73 V), which constitutes further evidence for the effective π -conjugation between the two DAZBI units in dimer **12a**.

To obtain further insight into the electronic structure of DAZBI and its dimer, we conducted density functional theory (DFT) calculations for the DAZBI monomer **8c** ($\text{R} = \text{Me}$) and its DAZBI dimer **12c** ($\text{R} = \text{Me}$) at the B3LYP/6-31G(d) level using the Gaussian 09 software package (Fig. S47 and S48†). The initial geometry was used from their X-ray crystal structures.

The HOMO and LUMO of **8c** are delocalized over the entire π -system, the distribution of which is similar to those of zethrene **1**, zethrene bisimide **2c** ($\text{R} = \text{Me}$), and diazazethrene **4**. Conversely, the LUMO levels decrease drastically in the order **1** (-2.34 eV) > **4** (-2.82 eV) > **2c** (-3.67 eV) > **8c** (-4.05 eV). This order clearly demonstrates that both the imide functionalities and the sp^2 -hybridized nitrogen atoms significantly stabilize the LUMO level. The LUMO level of **8c** (-4.05 eV) is lower than those of diazaperylene bisimide **6** (-3.84 eV) and diazaanthanthrene

Table 1 Redox potentials of **8a**, **12a**, and **14b**. All potentials are standardized to the ferrocene/ferrocenium (Fc/Fc^+) couple; supporting electrolyte: 0.1 M $[\text{Bu}_4\text{N}][\text{PF}_6]$; reference electrode: Ag/AgNO_3

	E_{ox1}/V	E_{ox2}/V	E_{ox3}/V	E_{ox4}/V	E_{red1}/V	E_{red2}/V	E_{red3}/V	E_{red4}/V	$\Delta E/\text{V}$
8a ^a	1.24	—	—	—	-0.49	-0.73	—	—	1.73
8a ^b	1.23	—	—	—	-0.44	-0.78	—	—	1.67
12a ^a	1.07	1.20	1.35	1.53	-0.36	-0.48	-0.73	-0.91	1.43
14b ^b	0.10	1.18	—	—	-1.76	-2.05	—	—	1.86

^a Conducted in CH_2Cl_2 . ^b Conducted in THF.



occupancies of 0.59 and 0.41, whereby the inversion proceeds along the shorter molecular axis. The main skeleton is highly planar with a mean plane deviation of 0.046 Å. The dianion core is separated from the two counter ions ($[\text{Co(III)Cp}_2]^+$), suggesting that there is negligible interaction between these ions. The C17–N3 bond length (1.367(9) Å) is comparable to the C21–N3 bond length (1.348(7) Å), consistent with an amine-type character of the central nitrogen atoms. The HOMA value of ring C (0.60) in **13** is higher than that of **8a** (0.07). These results indicate that the injection of two electrons into **8a** causes the relaxation of the bond-length alternation. The C–O bonds in **13** (1.22(2)/1.26(2) Å) are longer than those in **8a** (1.220(5)/1.214(6) Å), suggesting a weakened carbonyl vibration. This notion was corroborated using infrared (IR) absorption spectroscopy (**13**: 1634 cm^{-1} ; **8a**: 1699 cm^{-1} ; Fig. S52†) and theoretical calculations (Fig. S54†).

The cyclic voltammogram of **14b** in THF shows the first reduction and oxidation waves at -1.76 V and 0.10 V (vs. Fc/Fc^+), respectively (Fig. S46† and Table 1, line 4). These potentials are shifted negatively compared to those of neutral **8a** (Table 1, line 2). The electrochemical HOMO–LUMO gap (1.86 V) is slightly larger than that of the DAZBI monomer **8a** (1.67 V).

The UV/vis absorption and emission spectra of dianion **13** and dihydro species **14a** in DMSO are shown in Fig. 7. One drop of trifluoroacetic acid (TFA) was added to the solution of **14a** in order to suppress any spontaneous deprotonation (Fig. S69†). The photophysical parameters are summarized in Table S3.† The absorption and emission spectra of **13** resemble those of **14a**, except for an absorption at 508 nm. This similarity suggests highly similar electronic structures for these two compounds. These spectra were also reproduced well using TD-DFT calculations (Fig. S51†). The absorption and emission spectra of **13** and **14a** are well-resolved with small Stokes shifts of 333 and 408 cm^{-1} , respectively, suggesting a small structural relaxation in their excited states. Importantly, dianion **13** and dihydro species **14a** exhibit a red fluorescence with a quantum yield of 0.53 and 0.40, respectively. These values are higher than those of DAZBI **8** (0.10) and the PBI dianion (0.18).^{47–49} Given that DAZBI undergoes hydrogenation when treated with L-ascorbic acid to afford the highly emissive reduced species **14**, it should be possible to use DAZBI as a fluorescent sensor that responds to a reductive environment in biological systems.⁵¹

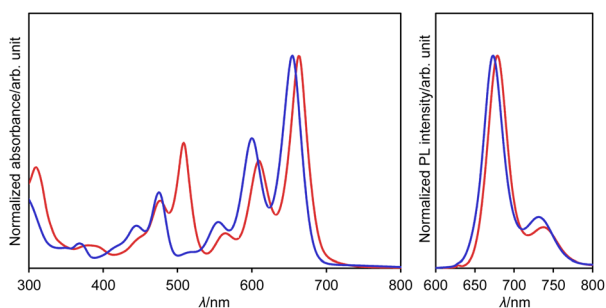


Fig. 7 UV/vis absorption and emission ($\lambda_{\text{ex}} = 630$ nm) spectra of **13** (red line) in DMSO and **14a** (blue line) in DMSO with one drop of TFA; λ : wavelength.

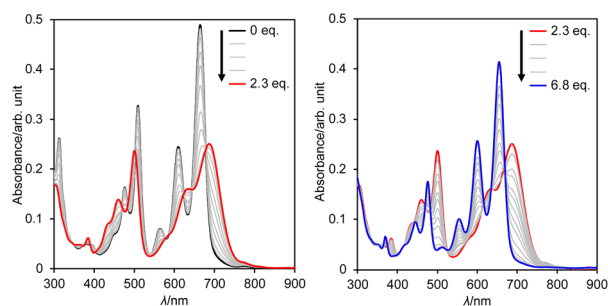


Fig. 8 Change in the absorption spectrum of **13** in DMSO upon addition of TFA; λ : wavelength.

Subsequently, we examined the interconversion between dianion **13** and dihydro species **14a**. Titration of a DMSO solution of **13** with TFA resulted in a two-step change of its absorption spectrum with clear isosbestic points (Fig. 8). The resulting absorption spectrum is identical to that of **14a**. The addition of 1,8-diazabicyclo[5.4.0]undec-7-ene (DBU) to this solution retrieved the original spectrum of **13**. This reversible acid–base response was also monitored using ^1H NMR spectroscopy (Fig. S71†).

Electron-conducting properties

An X-ray diffraction analysis of 3-pentyl-substituted DAZBI **8b** showed a quasi-one-dimensional packing structure with a π – π distance of 3.48(1) Å (Fig. S42†). Each molecule is disordered over two positions with relative occupancies of 0.58 and 0.42, whereby the inversion proceeds along the shorter molecular axis. The transfer integrals (t) between the LUMOs in its packing structure were simulated using DFT calculations at the PBEPBE/6-31G(d) level (Fig. S65 and Table S5†). Due to the crystal disorder, the transfer integrals must be considered for three combinations. The major and minor disordered structures are defined as **8b-A** and **8b-B**, respectively. The t values along the π -stacking direction are 89.1 meV for **8b-A–8b-A**, 7.6 meV for **8b-A–8b-B**, and 37.2 meV for **8b-B–8b-B**. Smaller t values (0.4–2.5 meV) were estimated along the horizontal directions.

Bottom-gate top-contact organic field-effect transistor (OFET) devices were fabricated from **8b**. An $\text{Al}_2\text{O}_3/\text{SiO}_2$ dielectric layer substrate was treated with a self-assembled monolayer of 12-cyclohexyldodecylphosphonic acid (CDPA),⁵² before a thin layer of **8b** was vacuum-deposited on the substrate (*ca.* 5×10^{-4} Pa 0.3 \AA s^{-1}). Gold electrodes were vacuum-deposited on the active layer as the source and drain electrodes. A polarization-optical-micrograph (POM) analysis of the deposited film afforded a dark image. An atomic-force-microscopy (AFM) analysis showed a smooth surface with tiny domains (Fig. S61†). Out-of-plane X-ray diffraction measurements did not show any obvious peaks (Fig. S62†). These results indicate that the thin layer is amorphous. Photoelectron-yield-spectroscopy measurements revealed an ionization potential of 5.75 eV (Fig. S63†). Using the onset of the absorption spectrum, the band gap of the obtained thin film was determined to be 1.68 eV (Fig. S64†). According to these results, the energy level of the conduction band was



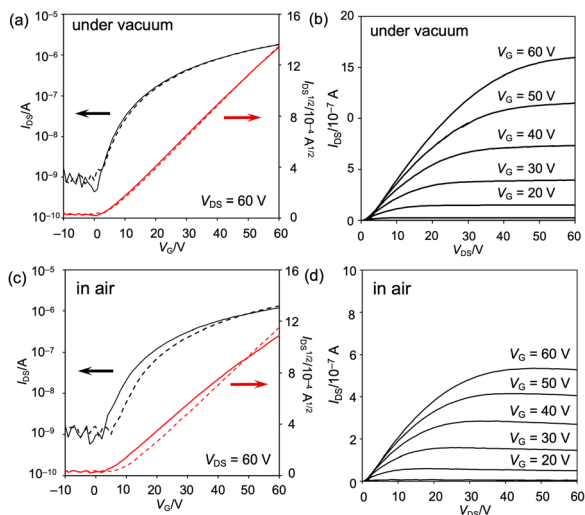


Fig. 9 Properties of the vacuum-deposited OFET device fabricated from **8b** (a, b) *in vacuo* and (c, d) under atmospheric conditions. (a, c) Transfer characteristics and (b, d) output characteristics.

estimated to be -4.07 eV, which matches well with the LUMO level of DAZBI.

The properties of the OFET device were measured at ambient temperature *in vacuo* (ca. 3×10^{-1} Pa) and under atmospheric conditions (Fig. 9 and S60 as well as Table S4†). The obtained OFET device exhibited typical n-type behavior. Under vacuum conditions, the maximum and average electron mobilities μ_e are 6.7×10^{-3} and $(6.1 \pm 0.5) \times 10^{-3} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, respectively, with an average on/off current ratio $I_{\text{on}}/I_{\text{off}}$ of $(3.4 \pm 1.8) \times 10^3$. Negligible current hysteresis was observed in the transfer characteristics. Notably, the devices exhibited a low threshold voltage, V_{th} , of 2 V, reflecting the extraordinary electron affinity of **8b**. Furthermore, exposure to air scarcely decreased the electron mobility, leading to a maximum and average electron mobility μ_e of 5.4×10^{-3} and $(4.6 \pm 0.7) \times 10^{-3} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, respectively. The current hysteresis was negligible, even under atmospheric conditions.

Conclusions

We synthesized the two diazazethrene bisimides (DAZBIs) **8a** and **8b**, which are nitrogen-doped zethrene derivatives with electron-withdrawing imide substituents. Moreover, the two DAZBI dimers **12a** and **12b** were prepared from **8a** and **8b**, respectively. Notably, DAZBI monomer **8a** exhibits an extraordinary electron affinity with a first reduction potential of -0.49 V. DAZBI dimer **12a** has an even higher electron affinity and the ability to accept multiple electrons due to the efficient electronic conjugation between its two DAZBI units. Treatment of DAZBI with cobaltocene afforded dianion **13**. Hydrogenation of DAZBI proceeded, even with L-ascorbic acid, to provide the dihydro species **14**. These reduced species exhibit both remarkable stability under ambient conditions and bright red fluorescence. In addition, these two reduced species are interconvertible upon treatment with acid and base. A thin film of

DAZBI is able to function as an air-stable n-type organic semiconductor with a low threshold voltage. Notably, DAZBI **8** is attractive compared to the structurally resembled species **6** and **7** in light of the superior electron-accepting ability and narrower HOMO–LUMO gap. The present study demonstrates that the choice of the main skeleton (herein zethrene) is crucial upon applying the design concept of the dual incorporation of both imide substituents and imine-type nitrogen atoms in order to design various functional materials with superb electron-accepting properties.

Data availability

Crystallographic data for **8a**, **8b**, **12b**, and **13** has been deposited at the CCDC under 2211115, 2211112, 2211113, and 2211114, respectively, and can be obtained from <https://www.ccdc.cam.ac.uk/>. The datasets supporting this article have been uploaded as part of the ESI material.†

Author contributions

The manuscript was written through contributions of all authors. All authors have approved of the final version of the manuscript. H. S. and N. F. designed and conducted the project and finalized the manuscript. K. T. carried out all the experiments including the synthesis, characterization, and OFET-fabrication. K. T. also wrote the first draft. K. M. and H. Y. supervised the evaluation of OFET characteristics.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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